

**UiO : Centre for Materials Science and Nanotechnology**  
University of Oslo

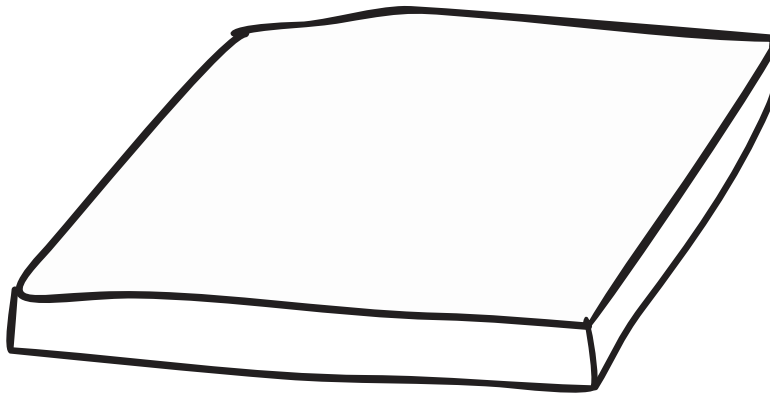
RECX

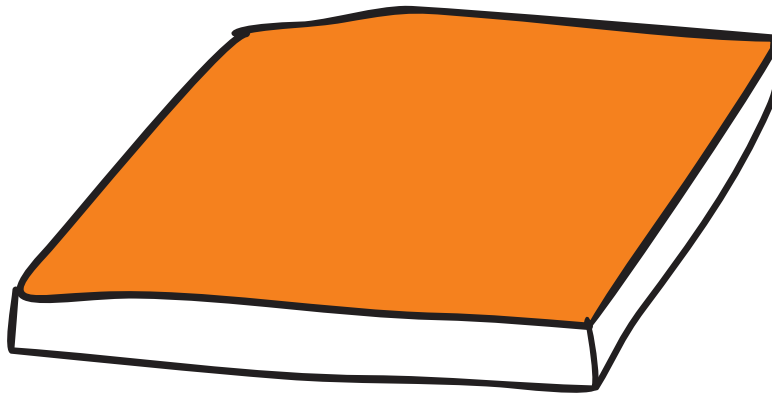
# Thin film metrology

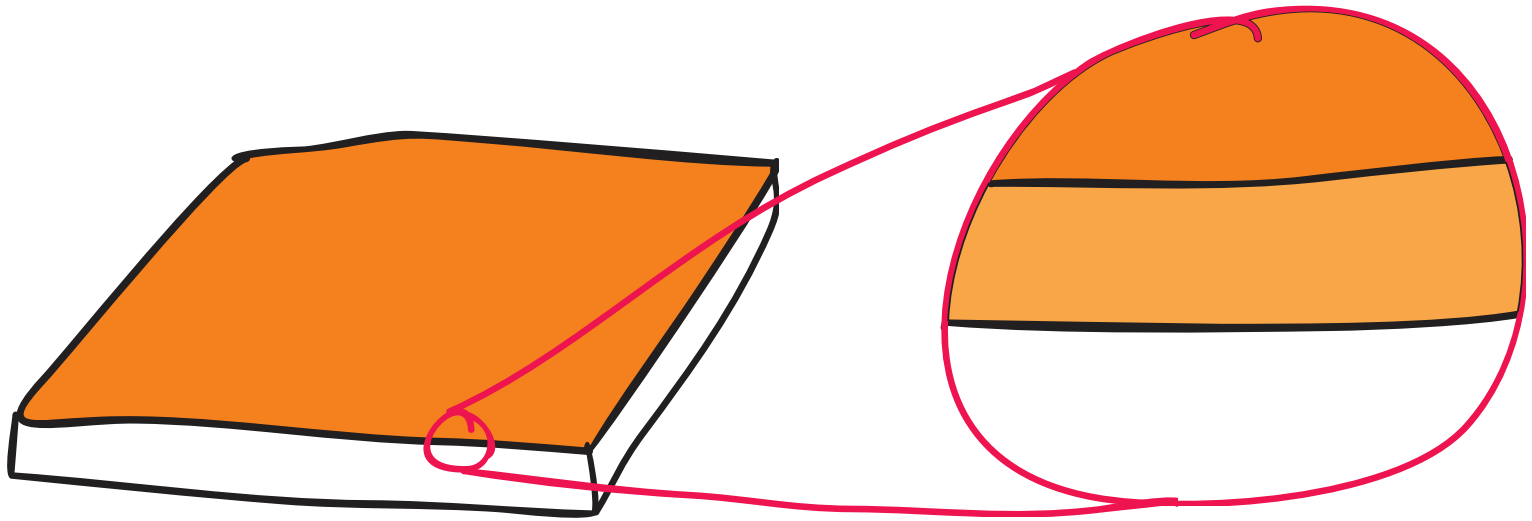


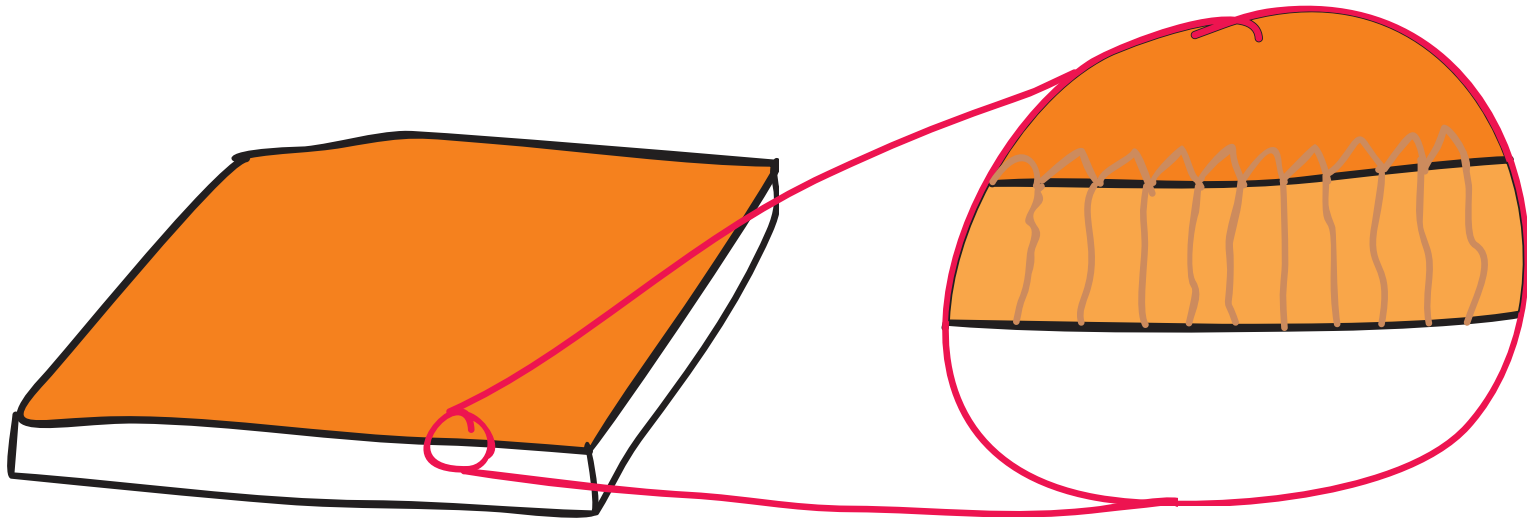
















## **XRR**

- Film thickness
- Roughness
- Density

## **GIXRD**

- Enhance material probed
- Phase
- Stress
- Depth profiling

## **HRXRD / RSM**

- Texture
- Strain
- Orientation



## **Phi-scan**

- In plane orientation

## **Rocking curve**

- Miscut
- Orientation

## **Polar plot**

- Texture

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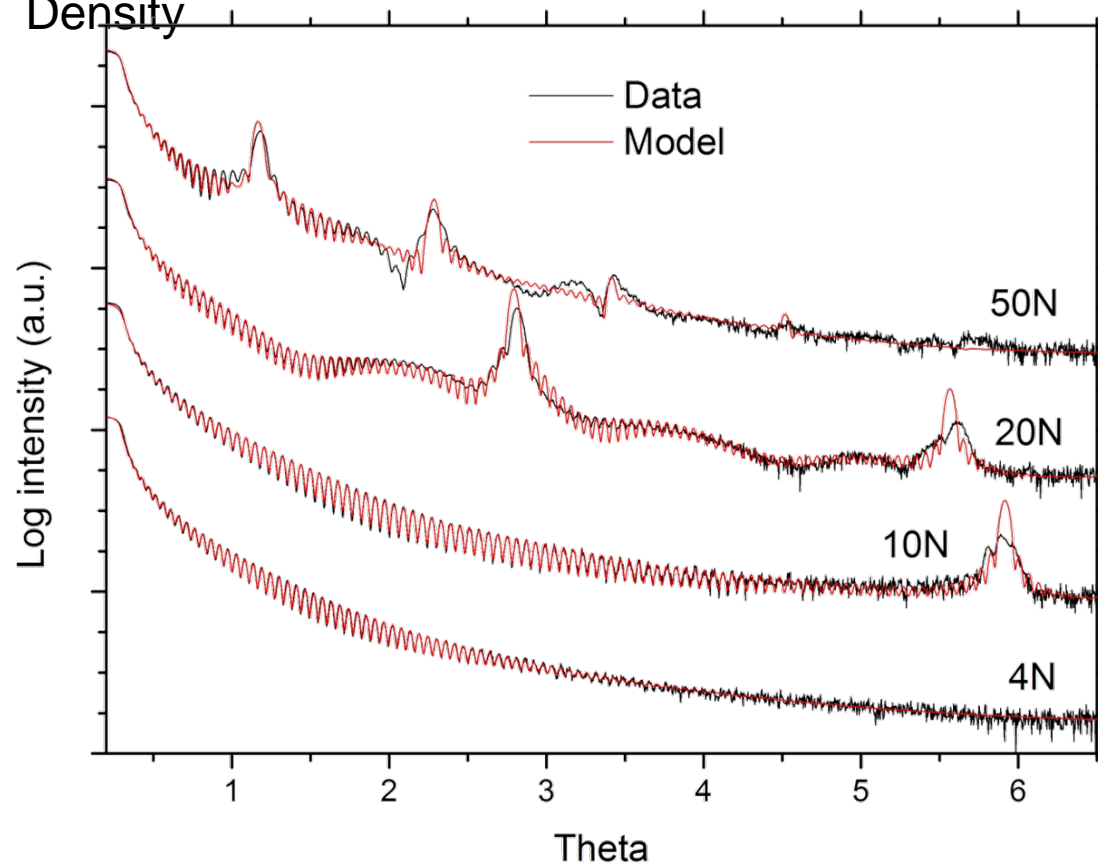
## Polar plot

- Texture

## XRR (X-ray reflectometry)

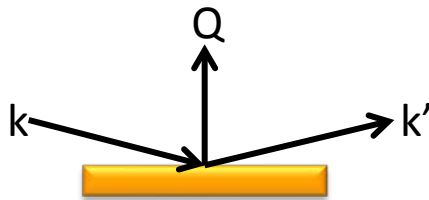
Reflectivity as function of angle to obtain information on:

- Film thickness
- Surface roughness
- Density



## XRR (X-ray reflectometry)

Scattering from surfaces and interfaces at low angles,  $\sim 0-8^\circ$



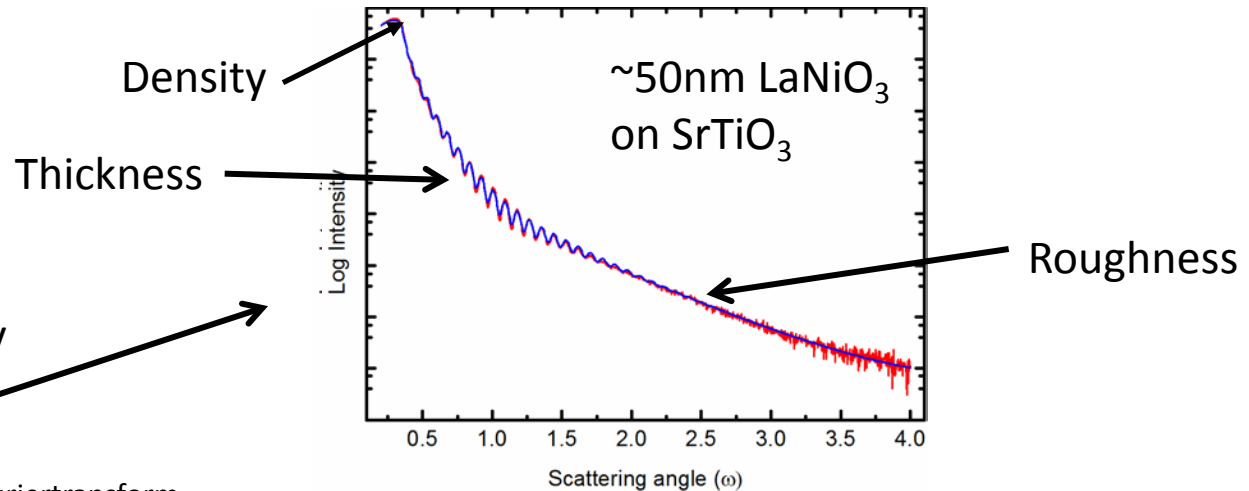
Scattering occurs from variations in electron density

$$I(q_z) = \frac{1}{q_z^4} \left| \int \frac{d\rho(z)}{dz} \exp(iq_z z) dz \right|^2$$

Fourier transform

Electron density

Variations in electron density arise from film thickness, roughness and density which can be determined for each layer



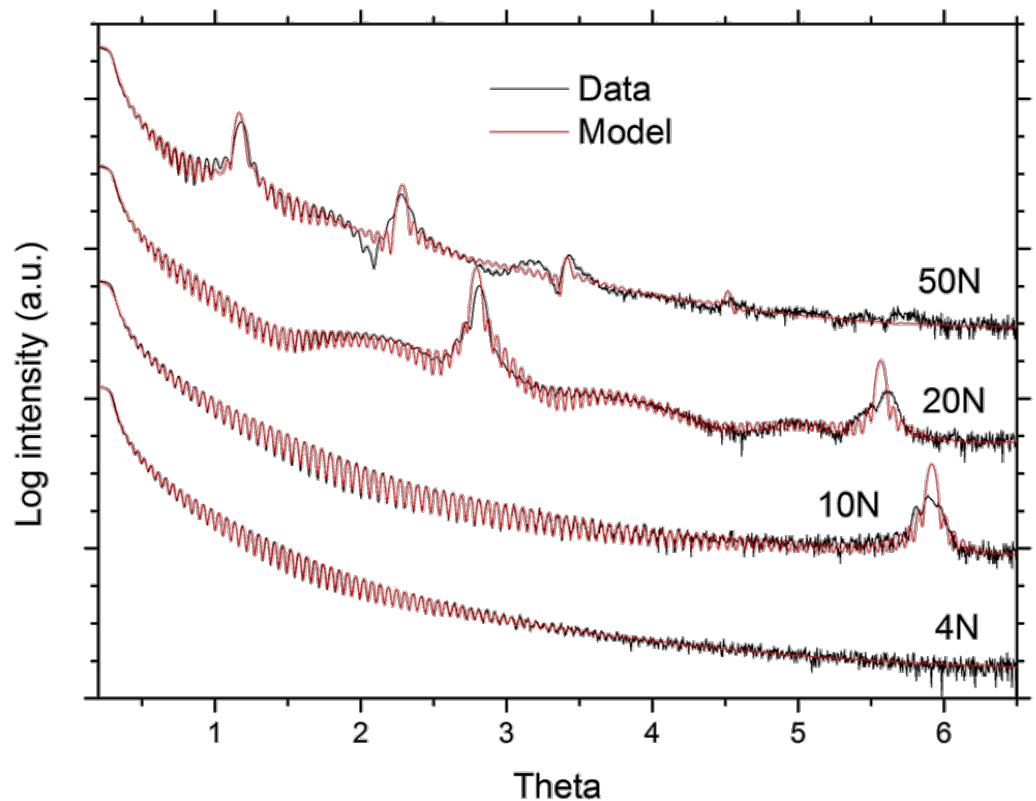
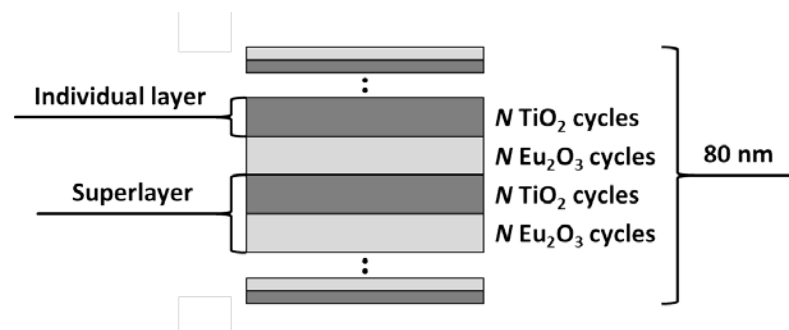
Refined parameters:

LaNiO<sub>3</sub> Thickness 48.98nm  
" Roughness 0.30 nm  
" Density 7.05 g/cm<sup>3</sup>

A surface layer of 1.4nm is also required to fully explain the results

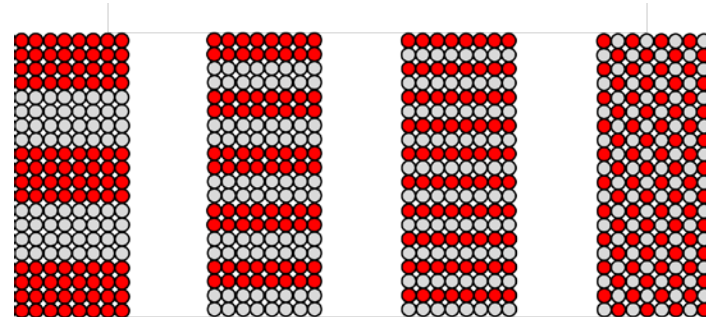
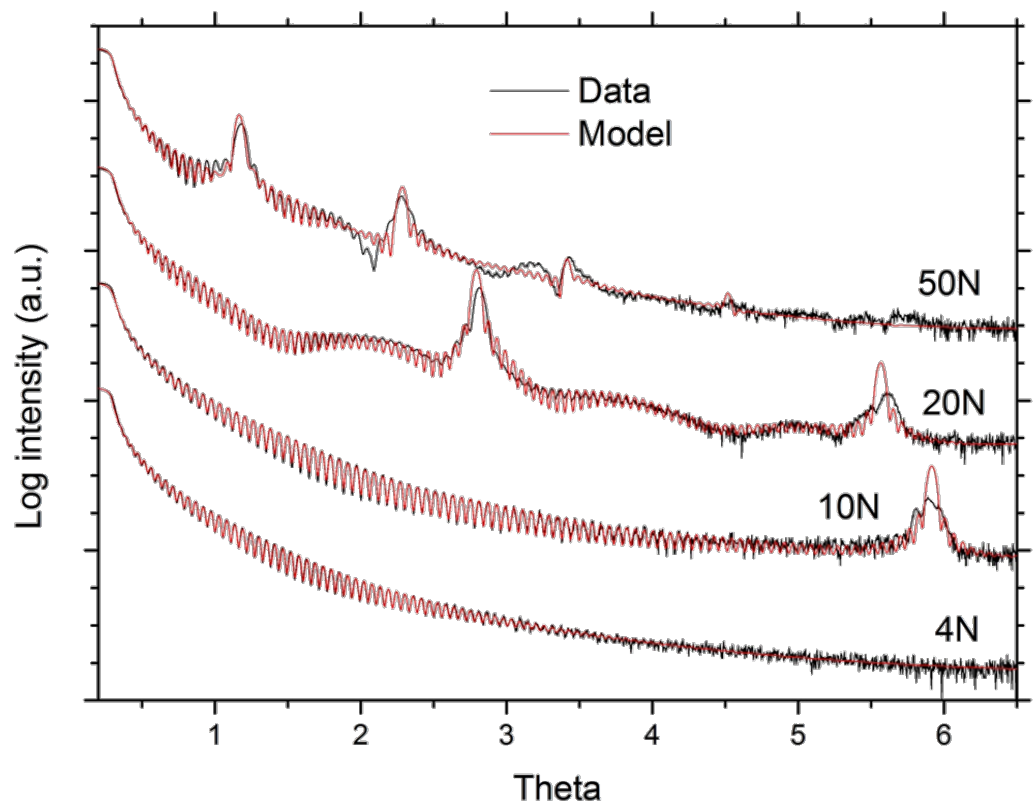
## XRR (X-ray reflectometry)

Layered thin films of  $\text{Eu}_2\text{O}_3$  and  $\text{TiO}_2$  grown by ALD as conversion material with the aim of controlling the Eu-Eu distance.



## XRR (X-ray reflectometry)

Layered thin films of  $\text{Eu}_2\text{O}_3$  and  $\text{TiO}_2$  grown by ALD as conversion material with the aim of controlling the Eu-Eu distance.



The double layer thicknesses:

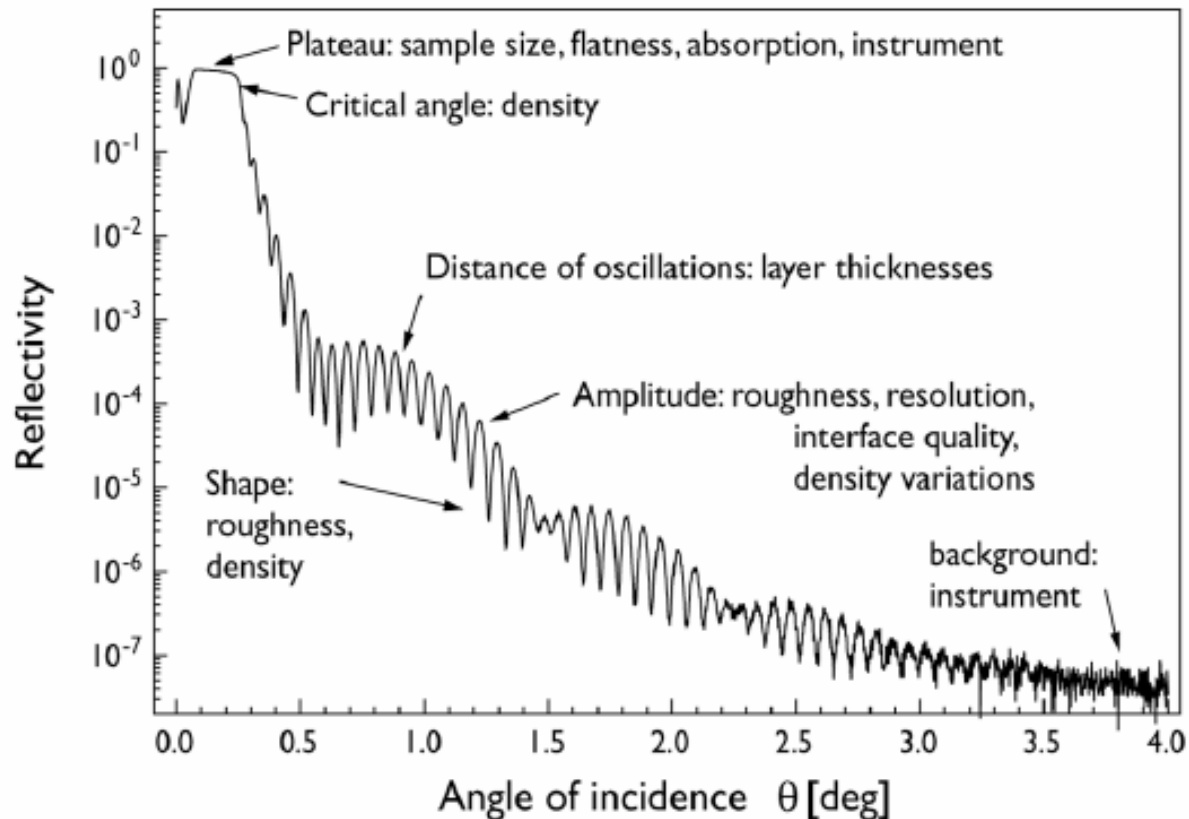
$$10\text{N} = 7.5 \text{ \AA}$$

$$20\text{N} = 15.9 \text{ \AA}$$

$$50\text{N} = 29.1 \text{ \AA}$$

Half the double layer thickness of the 10N sample,  $3.8 \text{ \AA}$ , is approx the same as the shortest Eu – Eu distance in cubic  $\text{Eu}_2\text{O}_3$ ,  $3.6 \text{ \AA}$

## XRR (X-ray reflectometry)



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## Phi-scan

- In plane orientation

## Rocking curve

- Miscut
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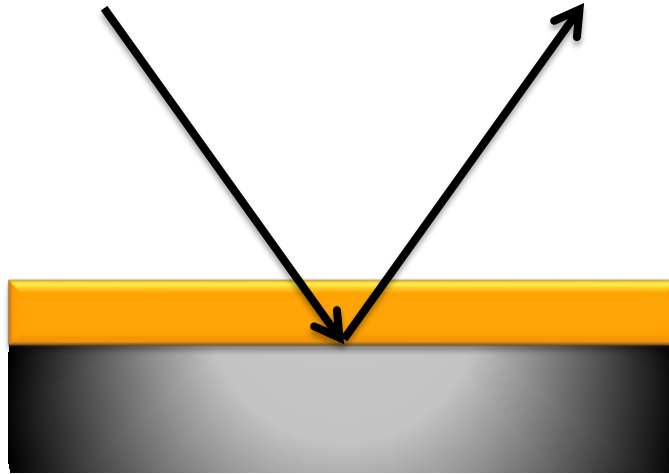
## Polar plot

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# GIXRD (Grazing incident x-ray diffraction)

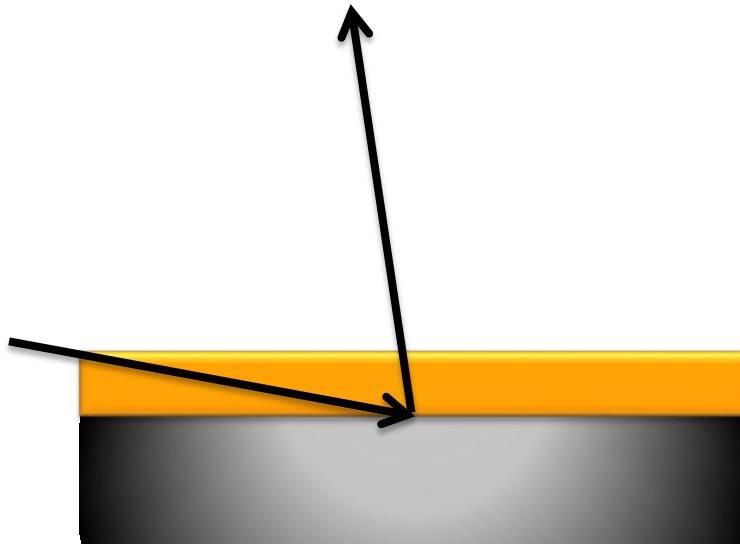
Increase the pathway through the sample



Conventional  $\theta$ -2 $\theta$

# GIXRD (Grazing incident x-ray diffraction)

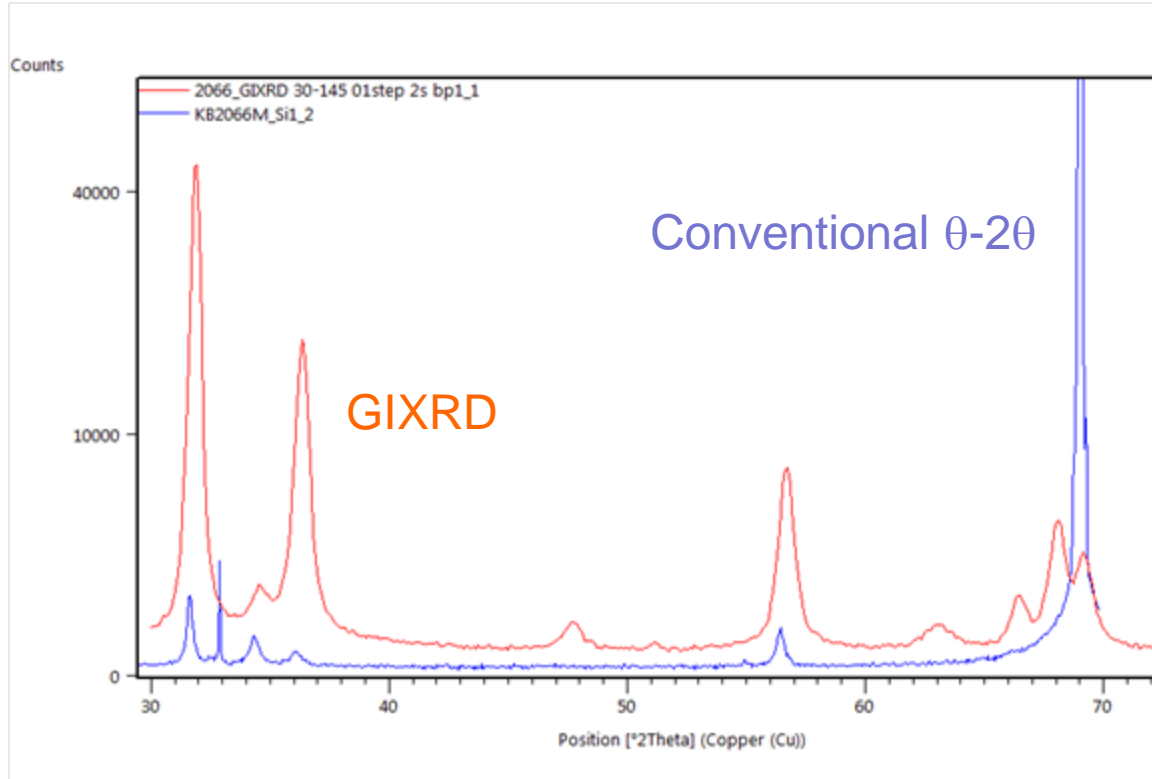
Increase the pathway through the sample



GIXRD

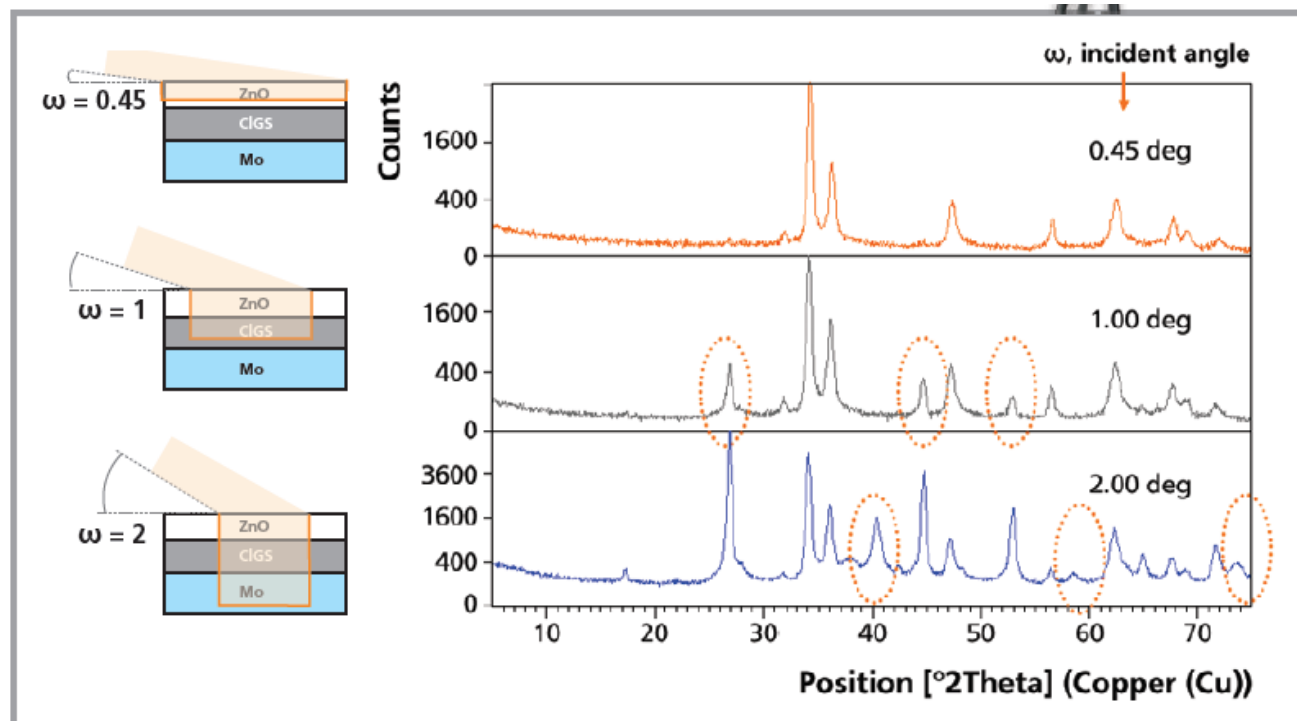
# GIXRD (Grazing incident x-ray diffraction)

A ZnO film of 200 nm deposited by ALD



# GIXRD (Grazing incident x-ray diffraction)

## Depth profile analysis



An example of depth probing on a CIGS solar structure, showing the different layers exposed to the parallel X-ray beam in a sequential mode by varying the incident angle. Top pattern is from the conductive oxide layer only, with CIGS coming in (middle, highlighted) and next the Mo metal contact layer appearing (bottom diagram, Mo peaks highlighted).

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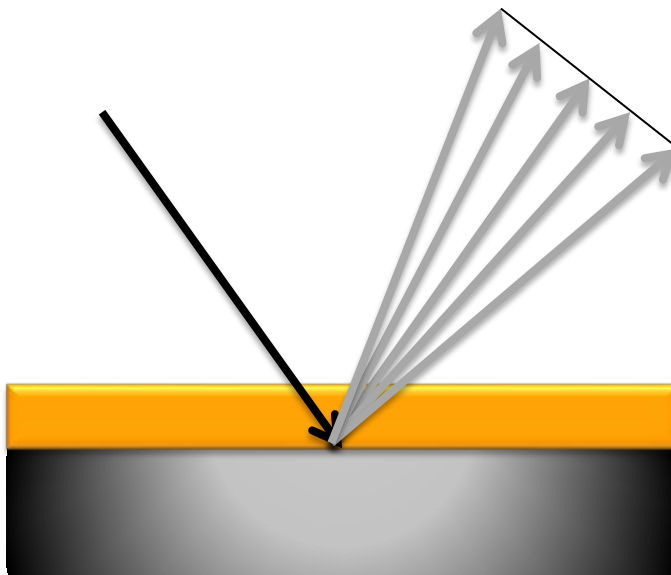
- Miscut
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## Polar plot

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## HRXRD (High-resolution x-ray diffraction)

Increase the pathway through the sample



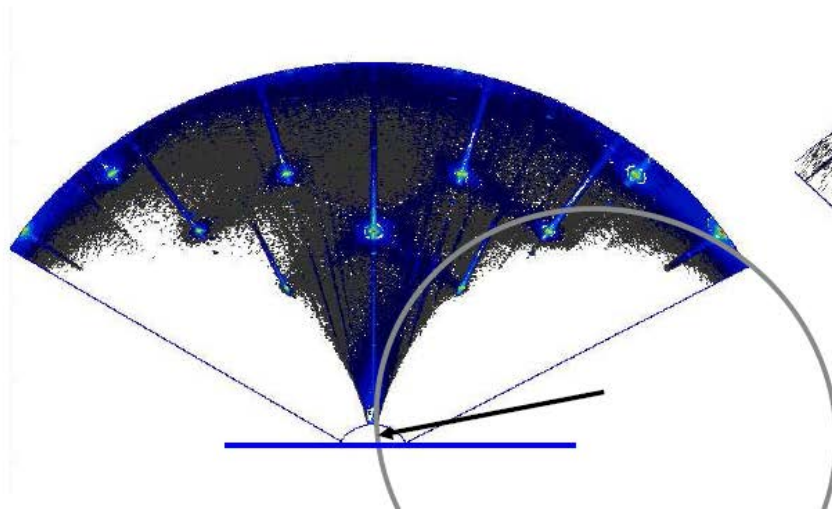
## HRXRD (High-resolution x-ray diffraction)

Map the reciprocal space to obtain information on:

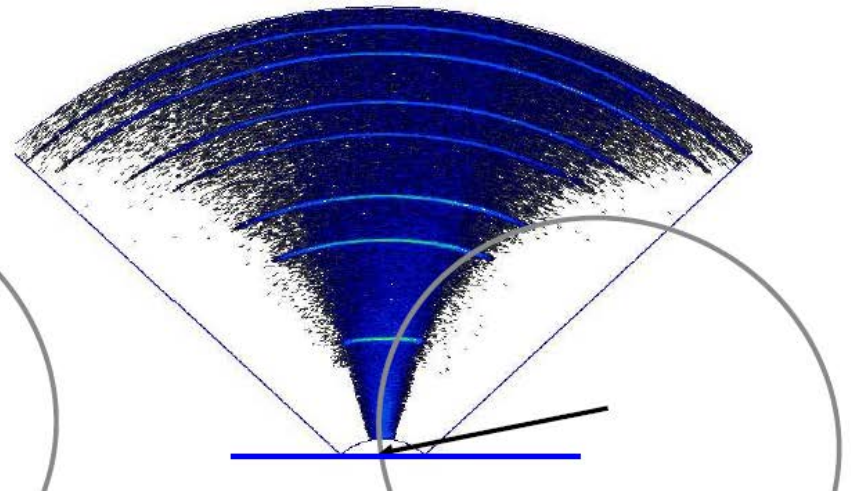
- Orientation
- Strain
- Texture ... and a lot more...



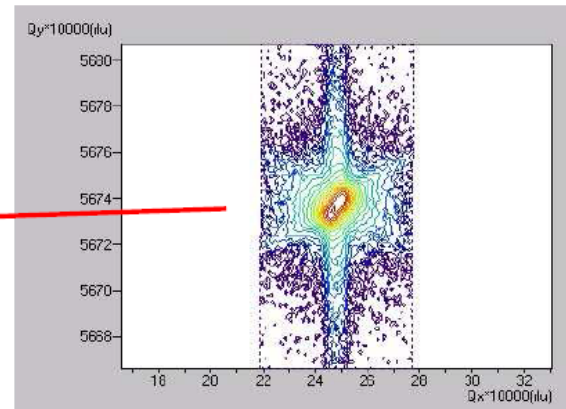
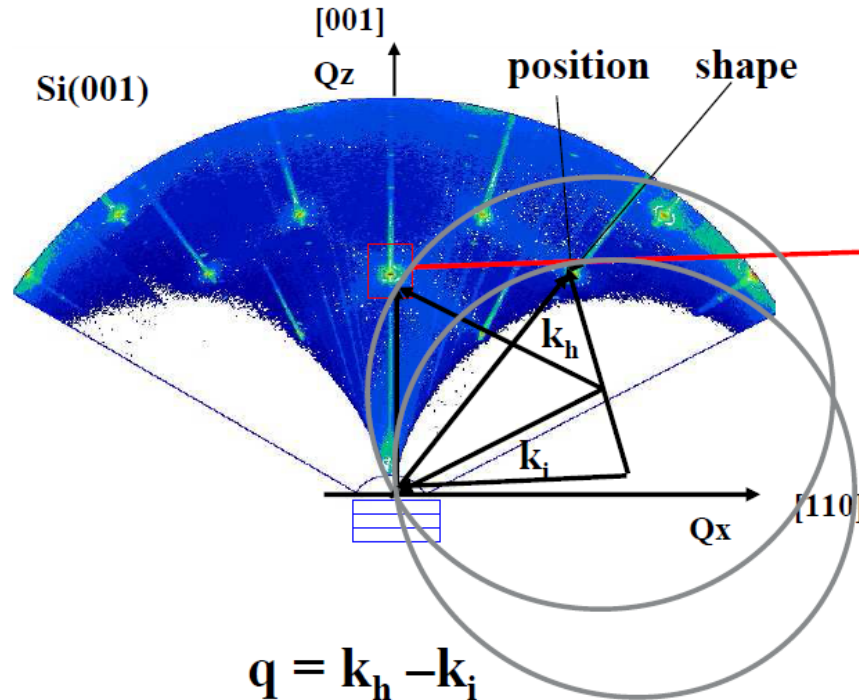
single crystal



poly crystal



# HRXRD (High-resolution x-ray diffraction)

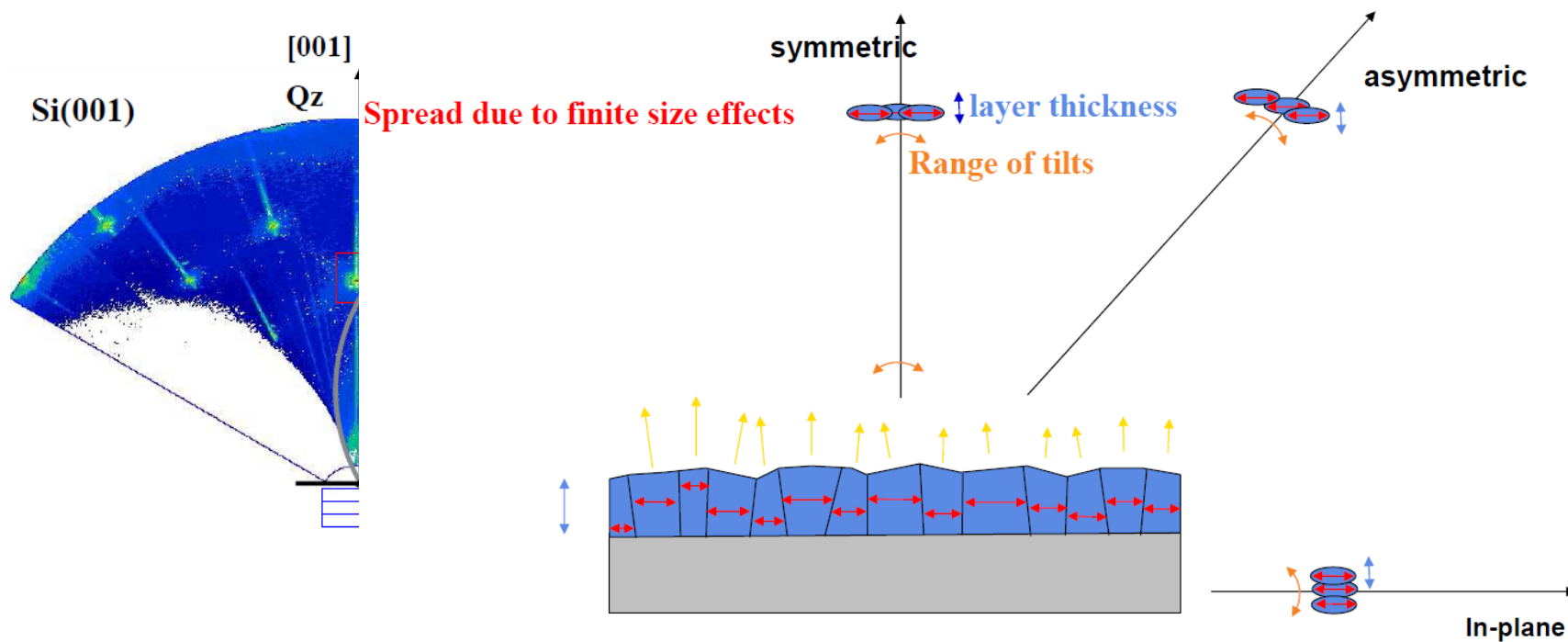


$$\mathbf{q} = \mathbf{k}_h - \mathbf{k}_i$$

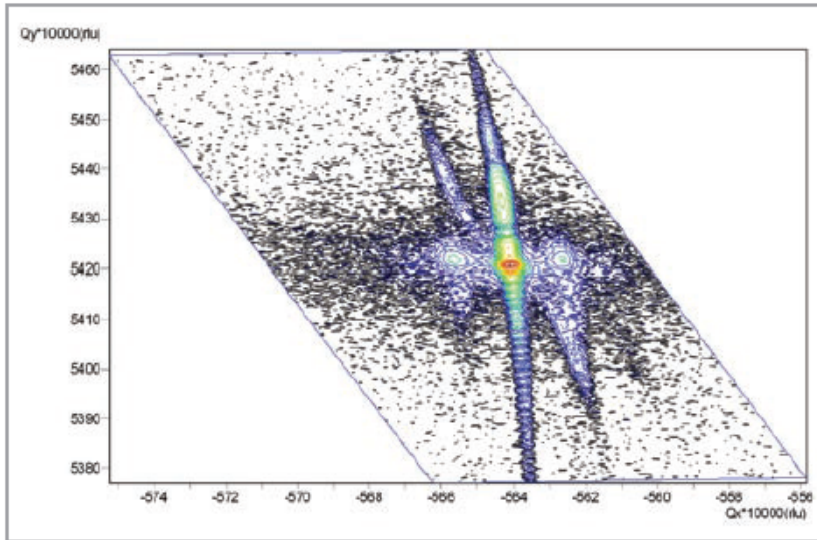
$$|\mathbf{q}| = 2\pi/d$$



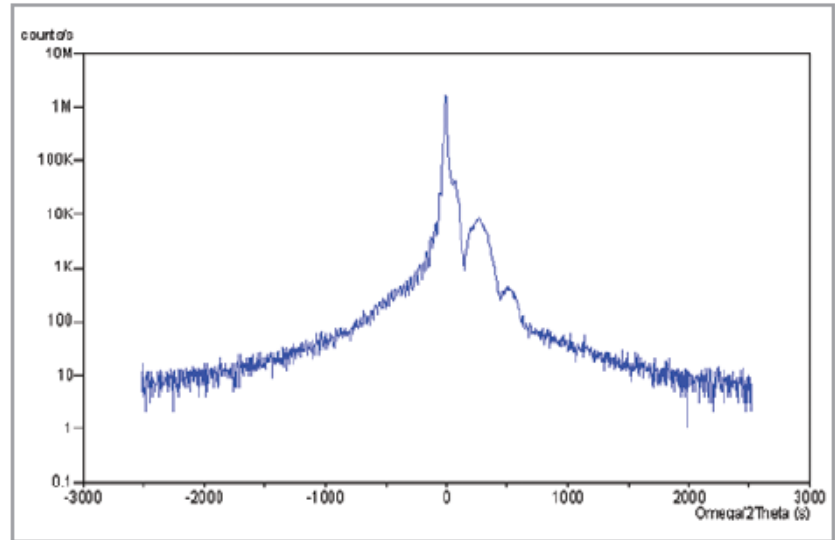
# HRXRD (High-resolution x-ray diffraction)



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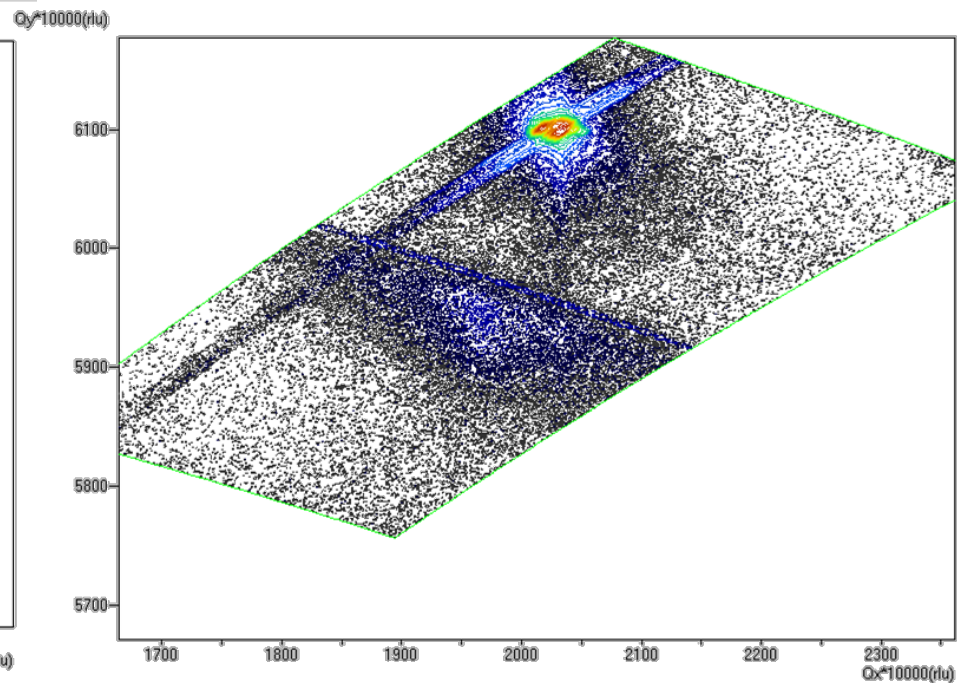
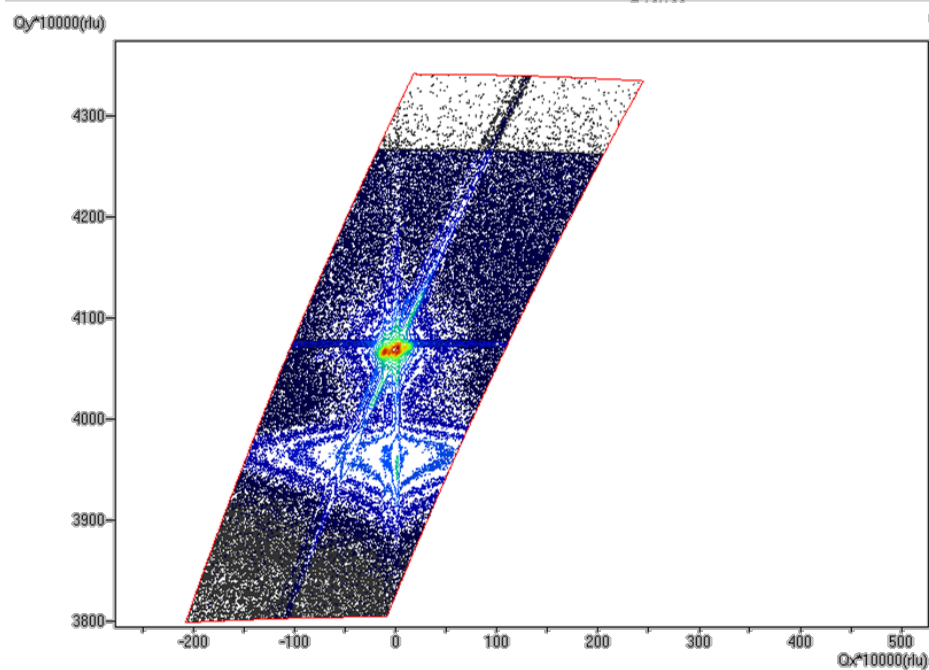
*A reciprocal space map (RSM) of a GaAs based epitaxial solar cell structure*



*A rocking curve diagram (RC) of an epitaxial solar cell structure around the (004) reflection of the GaAs substrate*

# HRXRD (High-resolution x-ray diffraction)

Film of  $\text{NaNbO}_3$  on  $\text{LaAlO}_3$



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